



PNP MEDIUM POWER TRANSISTORS IN SOT89

Features

- BV_{CEO} > -45V, -60V & -80V
- I_C = -1A Continuous Collector Current
- I_{CM} = -2A Peak Pulse Current
- Low Saturation Voltage V_{CE(SAT)} < -500mV @ -0.5A
- Gain Groups 10 and 16
- Complementary NPN Types: BCX54, 55 and 56
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Leads; Solderable per MIL-STD-202 Method 208 @3
- Weight: 0.052 grams (Approximate)

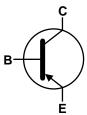
Applications

- Medium Power Switching or Amplification Applications
- AF Driver and Output Stages

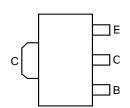








Device Symbol



Top View Pin-Out

Ordering Information (Notes 4 & 5)

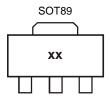
Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
BCX51TA	AEC-Q101	AA	7	12	1,000
BCX51-13R	AEC-Q101	AA	13	12	4,000
BCX5110TA	AEC-Q101	AC	7	12	1,000
BCX5116TA	AEC-Q101	AD	7	12	1,000
BCX5116TC	AEC-Q101	AD	13	12	4,000
BCX52TA	AEC-Q101	AE	7	12	1,000
BCX5210TA	AEC-Q101	AG	7	12	1,000
BCX5216TA	AEC-Q101	AM	7	12	1,000
BCX5216QTA	Automotive	AM	7	12	1,000
BCX53TA	AEC-Q101	AH	7	12	1,000
BCX5310TA	AEC-Q101	AK	7	12	1,000
BCX5316TA	AEC-Q101	AL	7	12	1,000
BCX5316TC	AEC-Q101	AL	13	12	4,000
BCX5316-13R	AEC-Q101	AL	13	12	4,000
BCX5110TC	AEC-Q101	AC	13	12	4,000
BCX51TC	AEC-Q101	AA	13	12	4,000
BCX5210TC	AEC-Q101	AG	13	12	4,000
BCX5216TC	AEC-Q101	AM	13	12	4,000
BCX52TC	AEC-Q101	AE	13	12	4,000
BCX5310TC	AEC-Q101	AK	13	12	4,000
BCX53TC	AEC-Q101	AH	13	12	4,000
BCX5316QTA	Automotive	Refer to http://diodes.com/datasheets/BCX5316Q.pdf			

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally
 the same, except where specified.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



Marking Information



xx = Product Type Marking Code, as follows:

 BCX51
 = AA
 BCX52
 = AE
 BCX53
 = AH

 BCX5110
 = AC
 BCX5210
 = AG
 BCX5310
 = AK

 BCX5116
 = AD
 BCX5216
 = AM
 BCX5316
 = AL

Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	BCX51	BCX52	BCX53	Unit
Collector-Base Voltage	V _{CBO}	-45	-60	-100	V
Collector-Emitter Voltage	V _{CEO}	-45	-60	-80	V
Emitter-Base Voltage	V _{EBO}		-5		V
Continuous Collector Current	Ic		-1		
Peak Pulse Collector Current	Ісм		-2		A
Continuous Base Current	I _B		-100		mA
Peak Pulse Base Current	I _{BM}		-200		

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 6)		1		
Power Dissipation	(Note 7)	P _D	1.5	W	
	(Note 8)		2.0		
	(Note 6)		125		
Thermal Resistance, Junction to Ambient Air	(Note 7)	$R_{\theta JA}$	83	°C/W	
	(Note 8)		60		
Thermal Resistance, Junction to Lead	(Note 9)	$R_{\theta JL}$	13	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C		

ESD Ratings (Note 10)

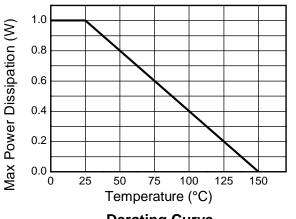
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

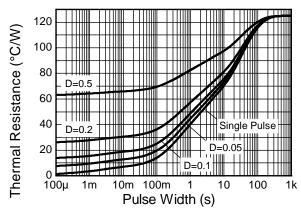
Notes:

- 6. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 7. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.
- 8. Same as Note 6, except the device is mounted on 50mm x 50mm 1oz copper.
- 9. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



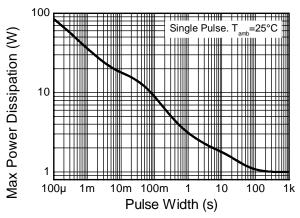
Thermal Characteristics and Derating Information



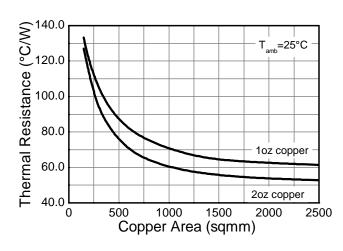


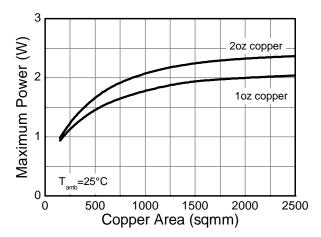
Derating Curve

Transient Thermal Impedance



Pulse Power Dissipation





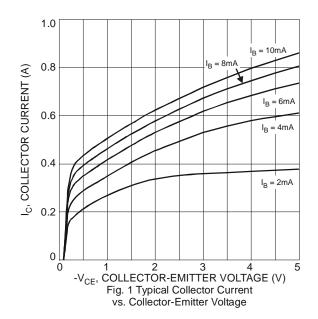


Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Callaster Dage	BCX51		-45	_	_	V	I _C = -100μA
Collector-Base Breakdown Voltage	BCX52	BV _{CBO}	-60				
Dicardown Voltage	BCX53		-100				
Callastan Fraittan	BCX51		-45	_	_		
Collector-Emitter Breakdown Voltage (Note 11)	BCX52	BV _{CEO}	-60			V	$I_C = -10mA$
breakdown voltage (Note 11)	BCX53		-80				
Emitter-Base Breakdown Voltage		BV _{EBO}	-5	_	_	V	I _E = -10μA
Oallester Oat Off Oarrest					-0.1		V _{CB} = -30V
Collector Cut-Off Current		I _{CBO}	_	_	-20	μA	$V_{CB} = -30V, T_J = +150$ °C
Emitter Cut-Off Current		I _{EBO}	_	_	-20	nA	$V_{EB} = -5V$
	All versions	h _{FE}	25	_	_	_	$I_C = -5mA$, $V_{CE} = -2V$
			40	_	250		$I_C = -150 \text{mA}, V_{CE} = -2 \text{V}$
Static Forward Current Transfer Ratio (Note 11)			25	_	_		$I_C = -500 \text{mA}, V_{CE} = -2 \text{V}$
(Note 11)	10 gain grp		63	_	160		$I_C = -150 \text{mA}, V_{CE} = -2 \text{V}$
	16 gain grp		100	_	250		$I_C = -150 \text{mA}, V_{CE} = -2 \text{V}$
Collector-Emitter Saturation Voltage (Note 11)		V _{CE(sat)}	_	_	-0.5	V	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
Base-Emitter Turn-On Voltage (Note 11)		V _{BE(on)}	_	_	-1.0	V	$I_C = -500 \text{mA}, V_{CE} = -2 \text{V}$
Transition Frequency		f⊤	150	_	_	MHz	$I_C = -50 \text{mA}, V_{CE} = -10 \text{V}$ f = 100MHz
Output Capacitance		Cobo	_		25	pF	$V_{CB} = -10V$, $f = 1MHz$

Note:

^{11.} Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



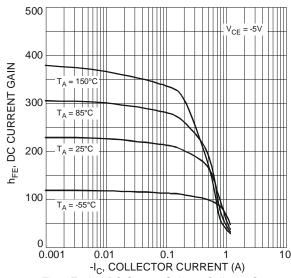


Fig. 2 Typical DC Current Gain vs. Collector Current



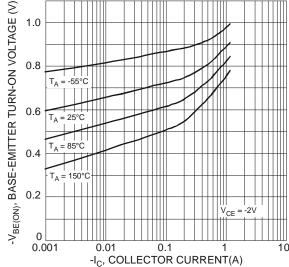


Fig 3 Typical Base-Emitter Turn-On Voltage vs. Collector Current

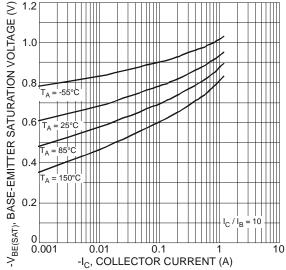


Fig. 5 Typical Base-Emitter Saturation Voltage vs. Collector Current

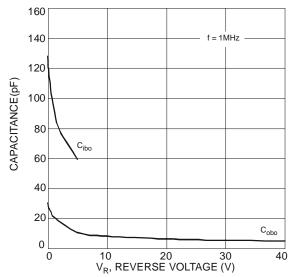


Fig. 7 Typical Capacitance Characteristics

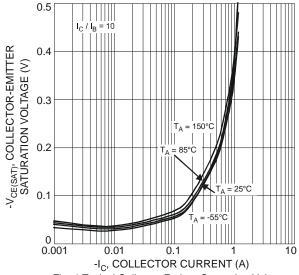


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

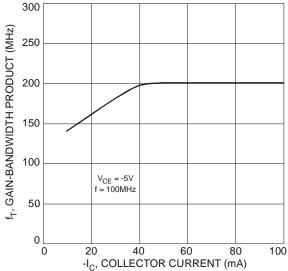
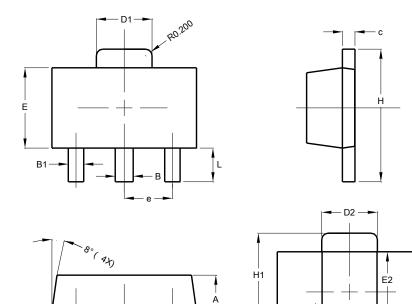


Fig. 6 Typical Gain-Bandwidth Product vs. Collector Current



Package Outline Dimensions

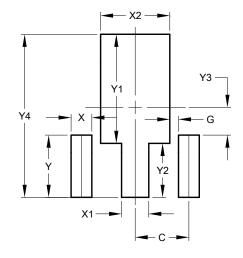
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	value (in mm)
С	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Υ	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

Value



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

7 of 7

www.diodes.com

Copyright © 2015, Diodes Incorporated

www.diodes.com